FAX NO.

# DEC 28 2005

CERTIFICATE OF TR Applicant(s): Burnham et al	ANSMISSION BY FACS	SIMILE (37 CFR 1.8)	Docket No. BUR920020109US1
Application No. 10/604,905	Filing Date 8/26/2003	Examiner Craig Thompson	Group Art Unit 2813
Invention: METHOD FOR	FABRICATING A NITRIDE	D SILICON-OXIDE GATE D	IELECTRIC
I hereby certify that this is being facsimile transmitte		uest for Reconsideration (1 <u>9 pa</u> (Identify type of correspondence) t and Trademark Office (Fax.	
On 12/28/2005 (Date)			
		Kim Dw (Typed or Printed Name of Per	ileski son Signing Certificate) re)
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# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Burnham et al.

Docket No.: BUR920020109US1

Serial No.: 10/604,905

Art Unit: 2813

Filed: August 26, 2003

Examiner: David S. Blum

Title: METHOD FOR FABRICATING A NITRIDED SILICON-OXIDE GATE DIELECTRIC

Honorable Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

#### REQUEST FOR RECONSIDERATION

This Request for Reconsideration is being filed in response to the Office Action mailed on October 25, 2005.